

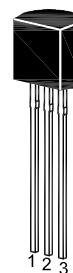
# ST 2SC1815

## NPN Silicon Epitaxial Planar Transistor

for switching and AF amplifier applications.

The transistor is subdivided into four groups, O, Y, G and L, according to its DC current gain. As complementary type the PNP transistor ST 2SA1015 is recommended.

On special request, these transistors can be manufactured in different pin configurations.



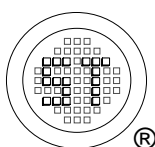
1. Emitter 2. Collector 3. Base  
TO-92 Plastic Package

### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	60	V
Collector Emitter Voltage	$V_{CEO}$	50	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	150	mA
Base Current	$I_B$	50	mA
Power Dissipation	$P_{tot}$	400	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 55 to + 150	$^\circ\text{C}$

### Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit	
DC Current Gain at $V_{CE} = 6\text{ V}$ , $I_C = 2\text{ mA}$ Current Gain Group	O	$h_{FE}$	70	140	-
	Y	$h_{FE}$	120	240	-
	G	$h_{FE}$	200	400	-
	L	$h_{FE}$	350	700	-
		$h_{FE}$	25	-	-
at $V_{CE} = 6\text{ V}$ , $I_C = 150\text{ mA}$					
Collector Base Cutoff Current at $V_{CB} = 60\text{ V}$	$I_{CBO}$	-	100	nA	
Emitter Base Cutoff Current at $V_{EB} = 5\text{ V}$	$I_{EBO}$	-	100	nA	
Collector Emitter Saturation Voltage at $I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$	$V_{CE(sat)}$	-	0.25	V	
Base Emitter Saturation Voltage at $I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$	$V_{BE(sat)}$	-	1	V	
Gain Bandwidth Product at $V_{CE} = 10\text{ V}$ , $I_C = 1\text{ mA}$	$f_T$	80	-	MHz	
Output Capacitance at $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{ob}$	-	3	pF	



**SEMTECH ELECTRONICS LTD.**  
Subsidiary of Sino-Tech International (BVI) Limited



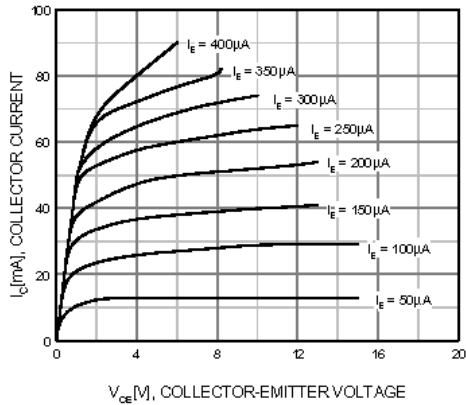


Figure 1. Static Characteristic

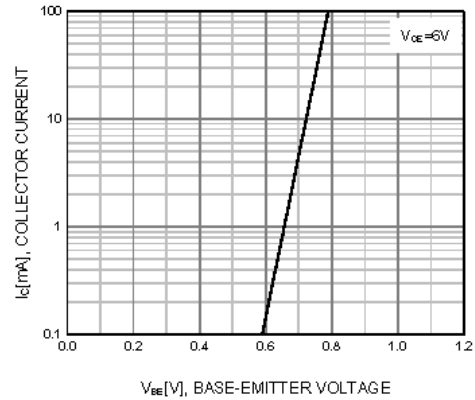


Figure 2. Transfer Characteristic

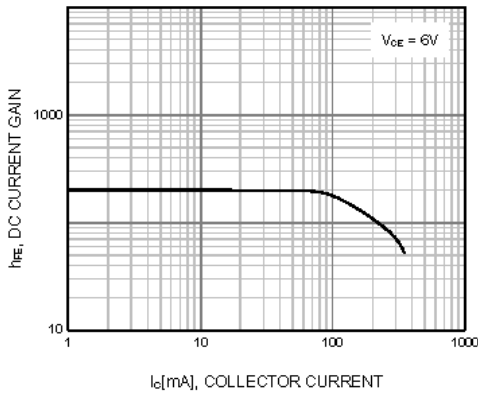


Figure 3. DC current Gain

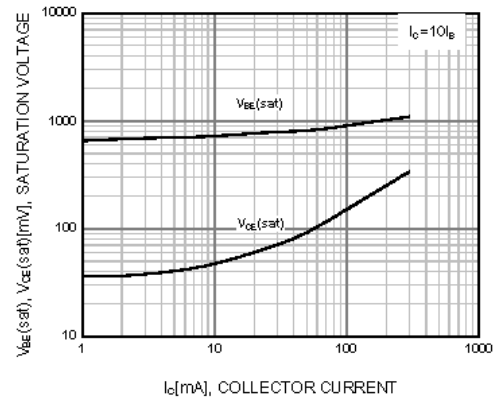


Figure 4. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

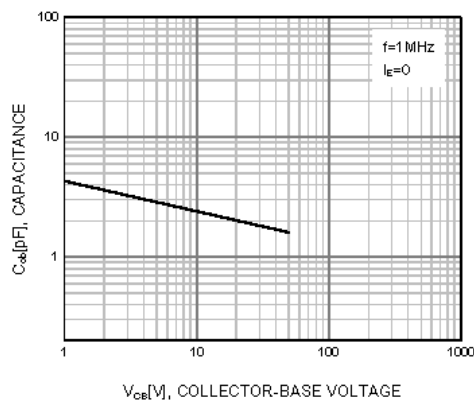


Figure 5. Output Capacitance

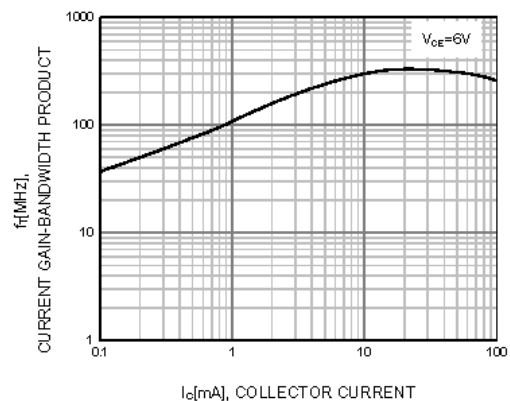


Figure 6. Current Gain Bandwidth Product

